

0.5 A max constant current LED driver

Features

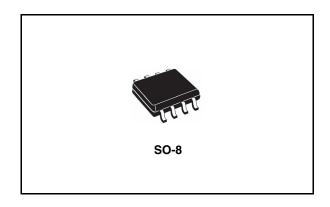
- Up to 40 V input voltage
- Less than 0.5 V voltage overhead
- Up to 0.5 A output current
- PWM dimming pin
- Shutdown pin
- LED disconnection diagnostic

Applications

- LED constant current supplying for varying input voltages
- Low voltage lighting
- Small appliances LED lighting
- Car LED lights

Description

The STCS05 is a BiCMOS constant current source designed to provide a precise constant current starting from a varying input voltage source. The main target is to replace discrete components solution for driving LEDs in low voltage applications such as 5 V, 12 V or 24 V giving benefits in terms of precision, integration and reliability.



The current is set with external resistor up to 0.5 A with a \pm 10 % precision; a dedicated pin allows implementing PWM dimming.

An open-drain pin output provides information on load disconnection condition.

Table 1. Device summary

Order code	Package	Packaging	
STCS05DR	SO-8	2500 parts per reel	

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Application diagram

V_{IN} 4.5V to 40V BAT46ZFILM R_{IN} 100 ohm \mathbf{C}_{BYP} 0.1µF V_{CC} **DRAIN** PWM STCS05 C_{DRAIN} 0.47μF OFF = DISC GND FB R_{FB} 0.2 ohm Load disconnection (Open Drain output)

Figure 1. Typical application diagram for 0.5 A LED current

Pin configuration STCS05

1 Pin configuration

Figure 2. Pin connections (top view)

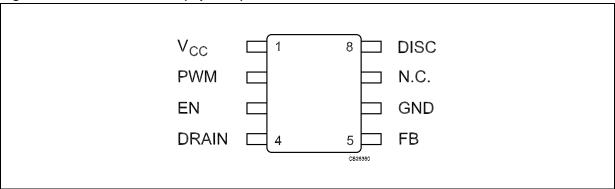


Table 2. Pin description

Pin n°	Symbol	Note
1	V _{CC}	Supply voltage
2	PWM	PWM dimming input
3	EN	Shutdown pin
4	DRAIN	Internal N-MOSFET drain
5	FB	External resistor connection for current set (N-MOSFET source)
6	GND	Ground
7	N.C.	In order to guarantee the device works properly it is mandatory to leave this pin floating
8	DISC	Load disconnection flag (open drain)

STCS05 **Maximum ratings**

Maximum ratings 2

Table 3. **Absolute maximum ratings**

Symbol	Parameter	Value	Unit
V _{CC}	DC supply voltage	-0.3 to +45	V
V_D	Drain voltage	-0.3 to +45	V
PWM, EN, DISC	Logic pins	-0.3 to + V _{CC} + 0.3	V
FB	Configuration pins	-0.3 to + 3.3	V
ESD	Human body model (all pins)	±2	kV
T _J ⁽¹⁾	Junction temperature	-40 to 150	°C
T _{STG}	Storage temperature range	-55 to 150	°C

^{1.} T_J is calculated from the ambient temperature T_A and the power dissipation P_D according the following formula: $T_J = T_A + (P_D \times R_{thJA})$. See *Figure 12* for details of max power dissipation for ambient temperatures higher than 25°C.

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

Table 4. Thermal data

Symbol	Parameter	SO-8	Unit
R _{thJC}	Thermal resistance junction-case	20	°C/W
R _{thJA}	Thermal resistance junction-ambient (1)	100	°C/W

^{1.} This value depends from thermal design of PCB on which the device is mounted.

Electrical characteristics STCS05

3 Electrical characteristics

Table 5. Electrical characteristics

(V_{CC} = 12 V; I_O = 100 mA; T_J = -40 °C to 125 °C; V_{DRAIN} = 1 V; C_{DRAIN} = 1 μ F; C_{BYP} = 100 nF typical values are at T_A = 25 °C, unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit		
V _{CC}	Supply voltage range		4.5		40	V		
	Output current range		1		500	mA		
Io	Output current	$R_{FB} = 0.2\Omega$		500		mA		
	Regulation (percentage with respect to V _{CC} = 12 V)	V _{CC} = 4.5 to 40V, I _O = 100mA; V _{DRAIN} = 1V	-1		+1	%		
V _{FB}	Feedback Voltage	I _O = 0 to 0.5A	90	100	110	mV		
		On Mode		450	750			
I _{CC}	Quiescent current (Measured on V _{CC} pin)	Shutdown Mode; V _{CC} = 5 to 12V			1	μA		
	- CC F7	Shutdown Mode; V _{CC} = 12 to 40V			3			
V	Dropout voltage (V to CND)	I _O = 100mA		0.12	0.16	V		
V _{DROP}	Dropout voltage (V _{DRAIN} to GND)	I _O = 0.5A		0.58	0.9			
LEAK _{DRAIN}	Drain leakage current	Shutdown; V _{DRAIN} = 40V			10	μA		
T _D	Delay on PWM signal (see	V _{PWM} rising, V _{CC} = 12V		3		- μs		
l 'D	Figure 3)	V_{PWM} falling, $V_{CC} = 12V$		1.2				
	Low level voltage	I _{SINK} = 5mA		0.2	0.5	V		
DISC	Leakage current	V _{DISC} = 5V			1	μA		
Disc	Load disconnection threshold	DISC Turn-ON		75		mV		
	(V _{DRAIN} -GND)	DISC Turn-OFF		110		IIIV		
Thermal	Shutdown temperature			155		°C		
Protection	Hysteresis		25					
Logic Input	s (PWM and EN)							
V _L	Input low level				0.4	V		
V _H	Input high level		1.2			V		
	EN, PWM leakage current	V _{EN} = 5V; V _{PWM} = 5V			2			
	EN input leakage current	V _{EN} = 40V			60	μA		
	PWM input leakage current	V _{PWM} = 40V			120			

Note: All devices 100 % production tested at $T_A = 25$ °C. Limits over the operating temperature range are guaranteed by design.

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STCS05 Timing

4 Timing

Figure 3. PWM and output current timing

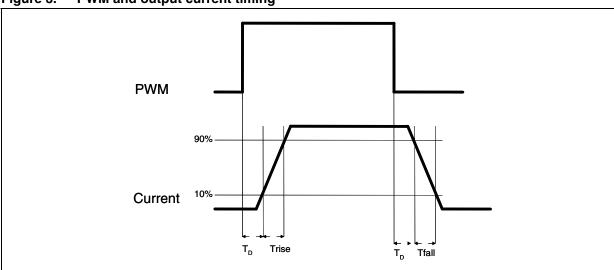
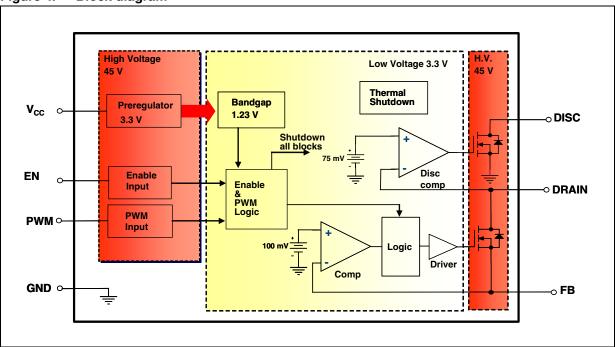


Figure 4. Block diagram



5 Typical performance characteristics

Figure 5. I_{DRAIN} vs V_{CC}, T_A = 25 °C

Figure 6. I_{DRAIN} vs R_{SET}

Figure 7. I_{DRAIN} vs temperature

Vcc[V]

VCC=12V - lout=0.5A IDRAIN [MA] -40 - 15 Temp [C]

Figure 8. V_{DROP} (including V_{FB}) vs temperature

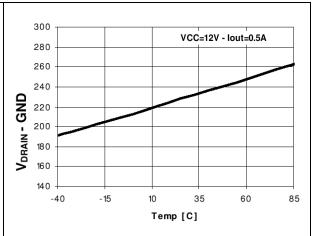


Figure 9. I_{CC} vs temperature

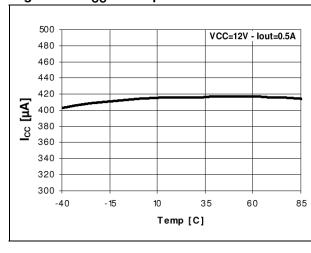
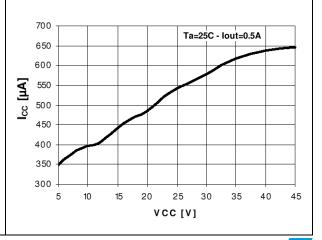


Figure 10. I_{CC} vs V_{CC}



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STCS05 Detail description

6 Detail description

The STCS05 is a BiCMOS constant current source designed to provide a precise constant current starting from a varying input voltage source. The main target is to replace discrete components solution for driving LEDs in low voltage applications such as 5 V, 12 V or 24 V giving benefits in terms of precision, integration and reliability.

6.1 Current setting

The current is set with an external sensing resistor connected to the FB pin. The feedback voltage is 100 mV, then a low resistor value can be chosen reducing power dissipation. A value between 1 mA and 500 mA can be set according to the resistor value, the resulting output current has a tolerance of \pm 10 %.

For instance, should one need a 350 mA LEDs current, R_F should be selected according to the following equation:

 $R_F = V_{FB} / I_{LEDs} = 100 \text{ mV} / 350 \text{ mA} = 284 \text{ m}\Omega$

6.2 Enable

When the enable pin is low the device completely off thus reducing current consumption to less than 1 μ A. When in shutdown mode, the internal main switch is off.

6.3 PWM dimming

The PWM input allows implementing PWM dimming on the LED current; when the PWM input is high the main switch will be on and vice versa. A typical frequency range for the input is from few Hertz to 50 kHz. The maximum dimming frequency is limited by the minimum rise/fall time of the current which is around 4 µs each. Above 50 kHz the current waveforms starts assuming a triangular shape.

While the PWM input is switching, the overall circuitry remains on, this is needed in order to implement a short delay time T_D (see *Figure 3*)

Since the PWM pin is controlling just the main switch, the overall circuitry is always on and it is able to control the delay time between the PWM input signal and the output current in the range of few μ s, this is important to implement synchronization among several light LED sources.

6.4 Diagnostic

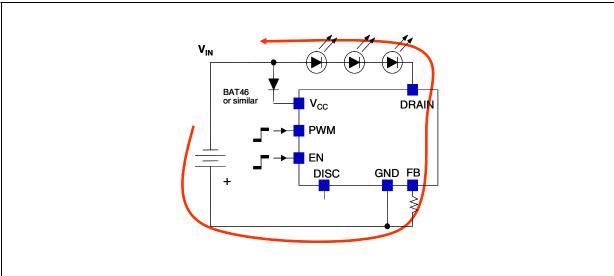
When STCS05 is in on mode (EN is high), the device is able to detect disconnection or fail of the LED string monitoring V_{DRAIN} pin. If V_{DRAIN} is lower than 75 mV the DISC pin is pulled low regardless the PWM pin status. This information can be used by the system to inform that some problem happens in the LEDs.

7 Application information

7.1 Reverse polarity protection

STCS05 must be protected from reverse connection of the supply voltage. Since the current sunk from V_{CC} pin is in the range of 450 μ A a small diode connected to V_{CC} is able to protect the chip. Care must be taken for the whole application circuit, especially for the LEDs, in fact, in case a negative voltage is applied between V_{IN} and GND, a negative voltage will be applied to the LED string that must have a total breakdown voltage higher than the negative applied voltage in order to avoid any damage.

Figure 11. Reverse polarity condition



7.2 Thermal considerations

The STCS05 is able to control a LED current up to 500 mA and able to sustain a voltage on the drain pin up to 40 V. Those operating conditions are however limited by thermal constraints, the thermal resistances shown in the thermal data section is the typical ones.

The power dissipation in the device can be calculated as follow:

$$P_D = (V_{DRAIN} - V_{FB}) \times I_{LED} + (V_{CC} \times I_{CC})$$

basing on this and on the thermal resistance and ambient temperature, the junction temperature can be calculated as:

$$T_J = R_{thJA} \times P_D + T_A$$

A typical application could be:

- Input Voltage: 12 V;
- 3 white LEDs with an typical V_F = 3.6 V;
- LEDs current: 350 mA;
- Package: SO-8;
- $T_A = 50 \,^{\circ}C;$

In this case $V_{DRAIN} = 12 - 3 \times 3.6 = 1.2 \text{ V}$

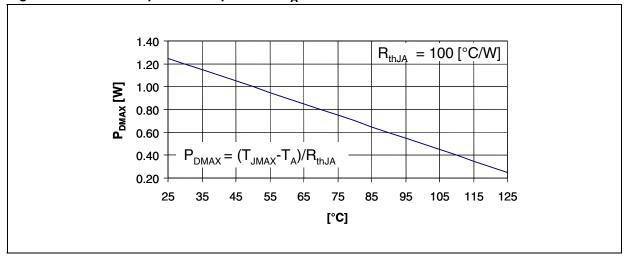
$$P_D = (1.2 - 0.1) \times 0.35 + 12 \times 0.5 \times 10^{-3} = 0.385 + 6 \times 10^{-3} = 391 \text{ mW}$$

The junction temperature will be:

$$T_J = 100 \times 0.391 + 50 = 89 \, ^{\circ}C.$$

The following pictures show the maximum power dissipation according to the ambient temperature:

Figure 12. Maximum power dissipation vs T_A for SO-8



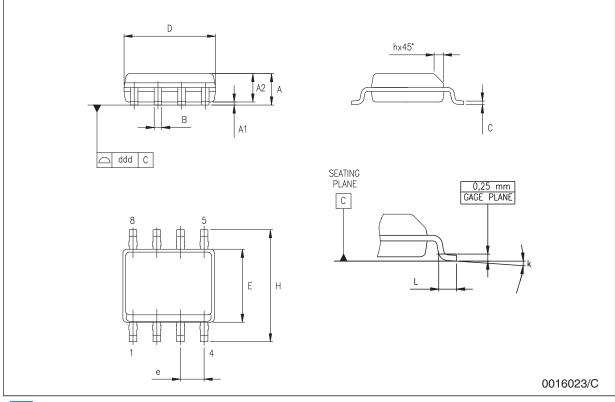
8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



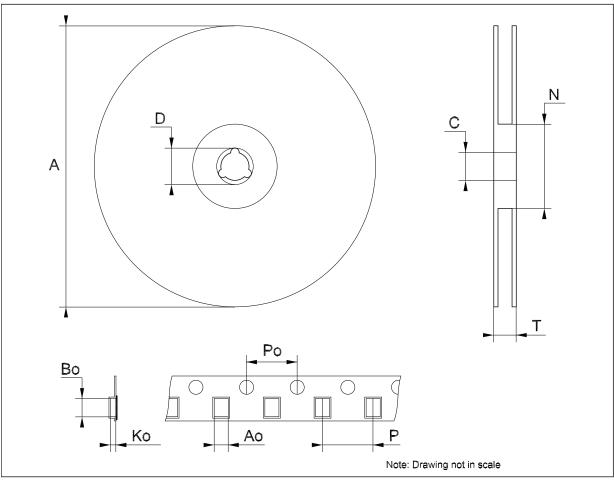
SO-8 mechanical data

Dim.	mm.			inch.		
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.
А	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.04		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	4.80		5.00	0.189		0.197
E	3.80		4.00	0.150		0.157
е		1.27			0.050	
Н	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	8° (max.)					
ddd			0.1			0.04



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Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	8.1		8.5	0.319		0.335
Во	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



STCS05 Revision history

9 Revision history

Table 6. Document revision history

Date	Revision	Changes		
03-Oct-2007	1	Initial release.		
15-Feb-2008	2	Modified: Figure 1 on page 3, Figure 4 on page 7, Figure 12 on page 11.		
05-May-2008	05-May-2008 3 Modified: <i>Table 2 on page 4</i> , pin 7 description.			
02-Jul-2008	4	Modified: <i>Table 5 on page 6</i> .		